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INA199-Q1

Reference

Design

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29

INA199-Q1 Automotive, 26-V, Bidirectional, Zero-Drift, Low- or High-Side, Voltage-Output, Current-Shunt Monitor

Technical

Documents

Features 1

- **Qualified for Automotive Applications**
- AEC-Q100 Qualified With the Following Results:
 - Device Temperature Grade 1: -40°C to +125°C Ambient Operating Temperature
 - Device HBM ESD Classification Level 2
 - **Device CDM ESD Classification Level C6** _
- Wide Common-Mode Range: -0.1 V to 26 V
- Offset Voltage: ±150 µV (Maximum) (Enables Shunt Drops of 10-mV Full-Scale)
- Accuracy:
 - ±1.5% Gain Error (Maximum Over Temperature)
 - 0.5-µV/°C Offset Drift (Maximum)
 - 10-ppm/°C Gain Drift (Maximum)
- Choice of Gains:
 - INA199B1-Q1: 50 V/V _
 - INA199B2-Q1: 100 V/V
 - INA199B3-Q1: 200 V/V
- Quiescent Current: 100 µA (Maximum)
- Package: 6-Pin SC70

2 Applications

- Mirrors •
- Brake Systems
- EGR Valves
- **Power Seats**
- **Body Control Modules**

Tools &

Software

- **Electric Windows**
- . Seat Heaters
- Wireless Charging

Description 3

The INA199-Q1 family is a series of voltage-output, current-sense amplifiers that can sense drops across shunts at common-mode voltages from -0.1 V to 26 V, independent of the supply voltage. Three fixed gains are available: 50 V/V, 100 V/V, and 200 V/V. The low offset of the zero-drift architecture enables current sensing with maximum drops across the shunt as low as 10-mV full-scale.

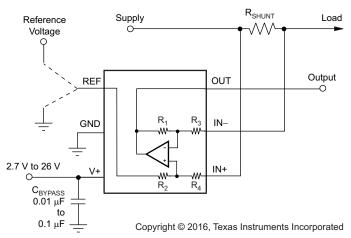
These devices operate from a single 2.7-V to 26-V power supply, drawing a maximum of 100 µA of supply current. All versions are specified from -40°C to +125°C, and are offered in a 6-pin SC70 package.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
INA199-Q1	SC70 (6)	2.00 mm × 1.25 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic





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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (March 2016) to Revision A

Released to production	1
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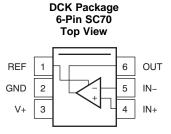
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5 Device Comparison Table

PRODUCT	GAIN	R ₃ AND R ₄	R ₁ AND R ₂
INA199B1-Q1	50 V/V	20 kΩ	1 MΩ
INA199B2-Q1	100 V/V	10 kΩ	1 MΩ
INA199B3-Q1	200 V/V	5 kΩ	1 MΩ

6 Pin Configuration and Functions



Pin Functions

PIN		1/0	DESCRIPTION		
NAME	NO.	I/O	DESCRIPTION		
GND	2	Analog	Ground		
IN–	5	Analog input	Connect to load side of shunt resistor		
IN+	4	Analog input	Connect to supply side of shunt resistor		
OUT	6	Analog output	Output voltage		
REF	1	Analog input	Reference voltage, 0 V to V+		
V+	3	Analog	Power supply, 2.7 V to 26 V		

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MI	N	MAX	UNIT	
Supply voltage				26	V	
Angles insult \mathcal{M} \mathcal{M} (2)	Differential (V _{IN+}) – (V _{IN-})	-2	26	26		
Analog inputs, V _{IN+} , V _{IN-} ⁽²⁾	Common-mode	GND	- 0.1	26	V	
REF input		GND	- 0.3	(V+) + 0.3	V	
Output		GND	- 0.3	(V+) + 0.3	V	
	Operating, T _A	-4	0	125		
Temperature	Junction, T _J			150	°C	
	Storage, T _{stg}	-6	5	150		

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) V_{IN+} and V_{IN-} are the voltages at the IN+ and IN- pins, respectively.

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7.2 ESD Ratings

			VALUE	UNIT
V _(ESD) Electrostatic dischar		Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000	
	Electrostatic discharge	Charged-device model (CDM), per AEC Q100-002 ⁽¹⁾	±1000	V
		Machine model (MM)	±100	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{CM}	Common-mode input voltage		12		V
Vs	Operating supply voltage (applied to V+)		5		V
T _A	Operating free-air temperature	-40		125	°C

7.4 Thermal Information

		INA199-Q1	
	THERMAL METRIC ⁽¹⁾	DCK (SC70)	UNIT
		6 PINS	
$R_{ extsf{ heta}JA}$	Junction-to-ambient thermal resistance	227.3	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	79.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	72.1	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	3.6	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	70.4	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	_	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.



7.5 Electrical Characteristics

at $T_A = 25^{\circ}$ C, $V_S = 5$ V, $V_{IN+} = 12$ V, $V_{SENSE} = V_{IN+} - V_{IN-}$, and $V_{REF} = V_S / 2$ (unless otherwise noted)

PARAMETER		R	TEST CONDITIONS	MIN	TYP	MAX	UNIT
INPUT						I	
V _{CM}	Common-mode inpu	ut range	$T_{A} = -40^{\circ}C \text{ to } +125^{\circ}C$	-0.1		26	V
CMR	Common-mode rejection		$V_{IN+} = 0 V \text{ to } 26 V, V_{SENSE} = 0 \text{ mV},$ $T_A = -40^{\circ}\text{C} \text{ to } +125^{\circ}\text{C}$	100	120		dB
V _{OS}	Offset voltage, RTI	1)	V _{SENSE} = 0 mV		±5	±150	μV
dV _{OS} /dT	V _{OS} vs temperature		$T_{A} = -40^{\circ}C \text{ to } +125^{\circ}C$		0.1	0.5	µV/°C
PSR	Power-supply reject	ion	$V_{S} = 2.7 V \text{ to } 18 V,$ $V_{IN+} = 18 V, V_{SENSE} = 0 \text{ mV}$		±0.1		μV/V
I _B	Input bias current		V _{SENSE} = 0 mV		28		μA
I _{OS}	Input offset current		V _{SENSE} = 0 mV		±0.02		μA
OUTPUT	-						
		INA199B1-Q1			50		
G	Gain	INA199B2-Q1			100		V/V
		INA199B3-Q1			200		
	Gain error		$V_{SENSE} = -5 \text{ mV to 5 mV},$ $T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$		±0.03%	±1.5%	
	Gain error vs tempe	erature	$T_{A} = -40^{\circ}C$ to +125°C		3	10	ppm/°C
	Nonlinearity error		$V_{SENSE} = -5 \text{ mV} \text{ to } 5 \text{ mV}$		±0.01%		
	Maximum capacitive	e load	No sustained oscillation		1		nF
VOLTAG	E OUTPUT ⁽²⁾		· ·				
	Swing to V+ power-supply rail		$R_L = 10 k\Omega$ to GND, $T_A = -40^{\circ}$ C to +125°C		(V+) – 0.05	(V+) - 0.2	V
	Swing to GND		$R_L = 10 k\Omega$ to GND, $T_A = -40$ °C to +125°C		(V _{GND}) + 0.005	(V _{GND}) + 0.05	V
FREQUE	NCY RESPONSE						
			C _{LOAD} = 10 pF, INA199B1-Q1		80		
GBW	Bandwidth		C _{LOAD} = 10 pF, INA199B2-Q1		30		kHz
			C _{LOAD} = 10 pF, INA199B3-Q1		14		
SR	Slew rate				0.4		V/µs
NOISE, F	RTI ⁽¹⁾						
	Voltage noise densi	ty			25		nV/√Hz
POWER	SUPPLY						
Vs	Operating voltage ra	ange	$T_{A} = -40^{\circ}C \text{ to } +125^{\circ}C$	2.7		26	V
l _Q	Quiescent current		V _{SENSE} = 0 mV		65	100	μA
	I _Q over temperature	1	$T_{A} = -40^{\circ}C \text{ to } +125^{\circ}C$			115	μA
TEMPER	ATURE RANGE						
	Specified range			-40		125	°C
	Operating range			-40		125	°C
θ _{JA}	Thermal resistance,	SC70			250		°C/W

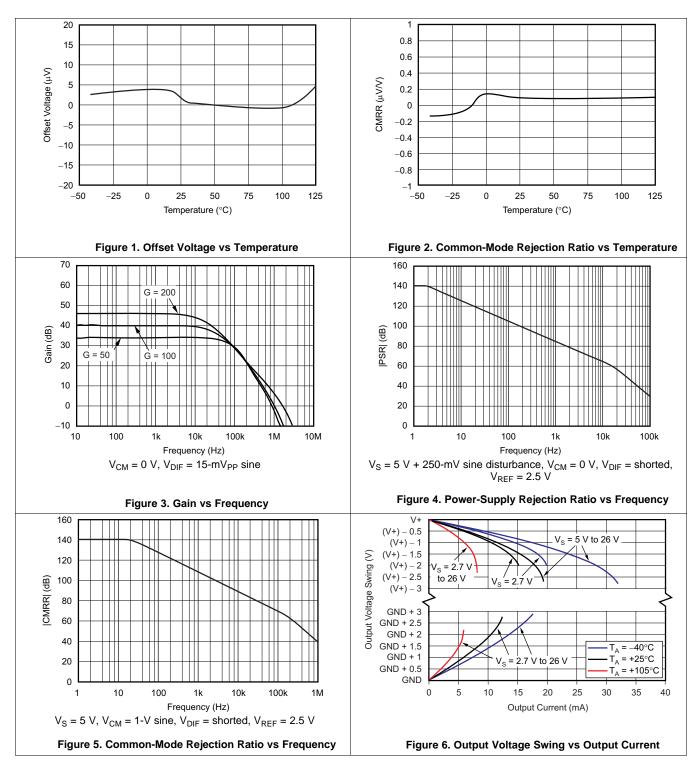
(1) RTI = referred-to-input.
(2) See typical characteristic curve, *Output Voltage Swing vs Output Current* (Figure 6).

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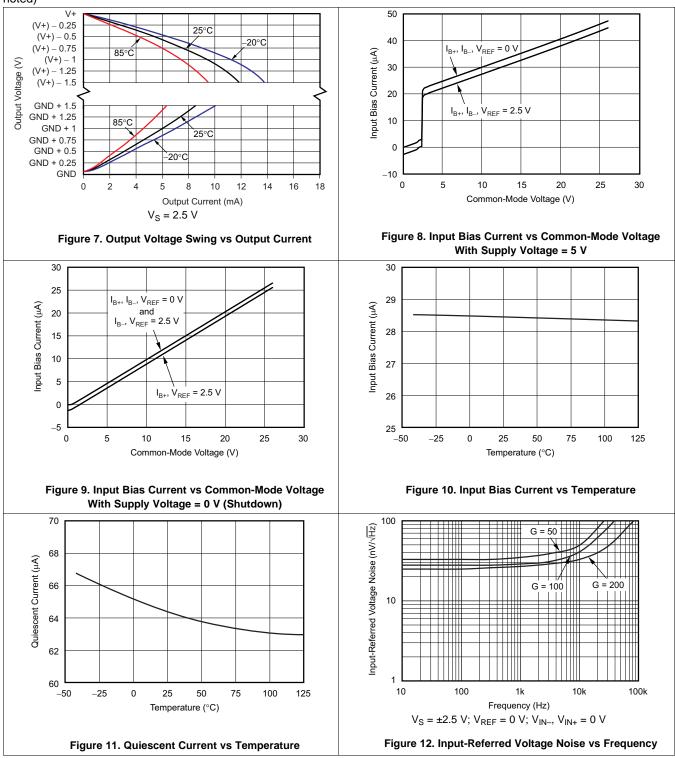
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7.6 Typical Characteristics





Typical Characteristics (continued)

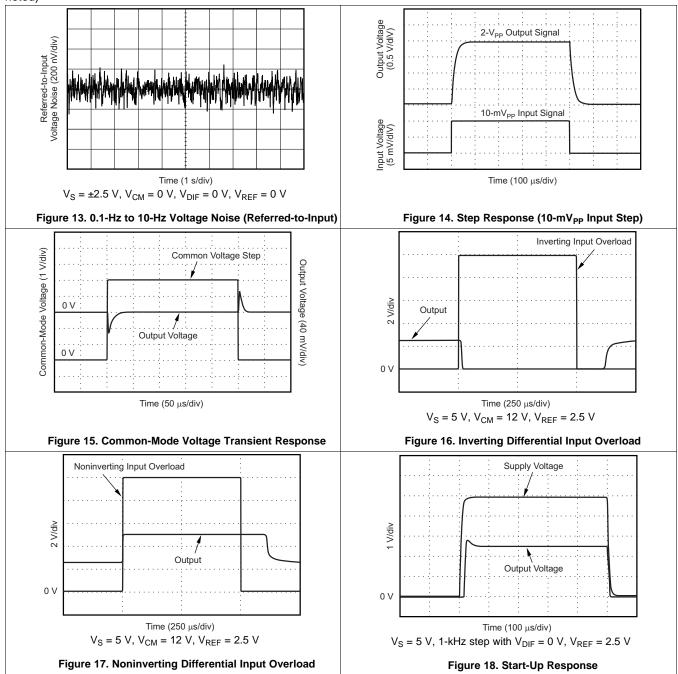


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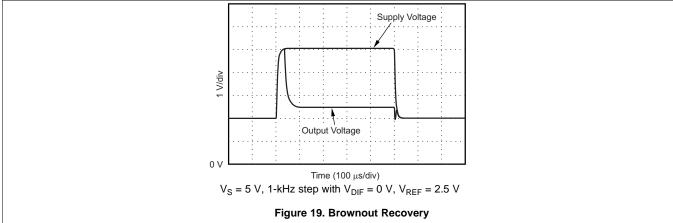
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Typical Characteristics (continued)





Typical Characteristics (continued)



INSTRUMENTS

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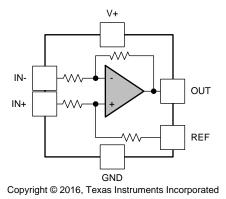
8 Detailed Description

8.1 Overview

The INA199-Q1 is a 26-V, common-mode, zero-drift topology, current-sensing amplifier that can be used in both low-side and high-side configurations. The device is a specially-designed, current-sensing amplifier that is able to accurately measure voltages developed across a current-sensing resistor on common-mode voltages that far exceed the supply voltage powering the device. Current can be measured on input voltage rails as high as 26 V and the device can be powered from supply voltages as low as 2.7 V.

The zero-drift topology enables high-precision measurements with maximum input offset voltages as low as 150 μ V with a maximum temperature contribution of 0.5 μ V/°C over the full temperature range of -40°C to +125°C.

8.2 Functional Block Diagram





8.3 Feature Description

8.3.1 Basic Connections

Figure 20 shows the basic connections for the INA199-Q1. The input pins, IN+ and IN–, must be connected as close as possible to the shunt resistor to minimize any resistance in series with the shunt resistor.

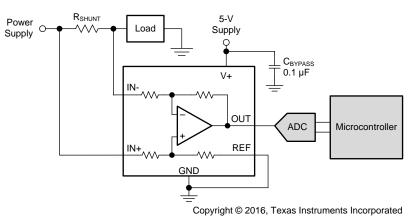


Figure 20. Typical Application

Power-supply bypass capacitors are required for stability. Applications with noisy or high-impedance power supplies may require additional decoupling capacitors to reject power-supply noise. Connect bypass capacitors close to the device pins.

8.3.2 Selecting R_s

The zero-drift offset performance of the INA199-Q1 offers several benefits. Most often, the primary advantage of the low offset characteristic enables lower full-scale drops across the shunt. For example, non-zero-drift current-shunt monitors typically require a full-scale range of 100 mV.

The INA199-Q1 series gives equivalent accuracy at a full-scale range on the order of 10 mV. This accuracy reduces shunt dissipation by an order of magnitude with many additional benefits.

Alternatively, there are applications that must measure current over a wide dynamic range that can take advantage of the low offset on the low end of the measurement. Most often, these applications can use the lower gain of 50 or 100 to accommodate larger shunt drops on the upper end of the scale. For instance, an INA199B1-Q1 operating on a 3.3-V supply can easily handle a full-scale shunt drop of 60 mV, with only 150 μ V of offset.



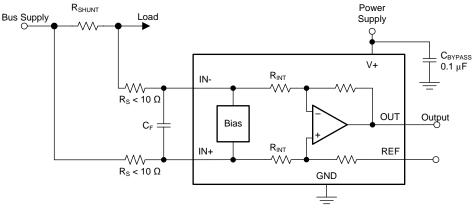
(1)

(2)

8.4 Device Functional Modes

8.4.1 Input Filtering

An obvious and straightforward filtering location is at the device output. However, this location negates the advantage of the low output impedance of the internal buffer. The only other filtering option is at the device input pins. This location, though, does require consideration of the $\pm 30\%$ tolerance of the internal resistances. Figure 21 shows a filter placed at the inputs pins.



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Figure 21. Filter at Input Pins

The addition of external series resistance, however, creates an additional error in the measurement so the value of these series resistors must be 10 Ω (or less if possible) to reduce any affect to accuracy. The internal bias network shown in Figure 21 present at the input pins creates a mismatch in input bias currents when a differential voltage is applied between the input pins. If additional external series filter resistors are added to the circuit, the mismatch in bias currents results in a mismatch of voltage drops across the filter resistors. This mismatch creates a differential error voltage that subtracts from the voltage developed at the shunt resistor. This error results in a voltage at the device input pins that is different than the voltage developed across the shunt resistor. Without the additional series resistance, the mismatch in input bias currents has little effect on device operation. The amount of error these external filter resistor add to the measurement can be calculated using Equation 1, where the gain error factor is calculated using Equation 2.

Gain Error Factor = -

$$(1250 \times R_s) + (1250 \times R_{INT}) + (R_s \times R_{INT})$$

 $(1250 \times R_{INT})$

where:

- R_{INT} is the internal input resistor (R_3 and R_4) and
- R_S is the external series resistance

The amount of variance in the differential voltage present at the device input relative to the voltage developed at the shunt resistor is based on both the external series resistance value and the internal input resistors, R_3 and R_4 (or R_{INT} , as shown in Figure 21). The reduction of the shunt voltage reaching the device input pins appears as a gain error when comparing the output voltage relative to the voltage across the shunt resistor. A factor can be calculated to determine the amount of gain error that is introduced by the addition of external series resistance. The equation used to calculate the expected deviation from the shunt voltage to what is measured at the device input pins is given in Equation 2.



Device Functional Modes (continued)

With the adjustment factor equation including the device internal input resistance, this factor varies with each gain version, as listed in Table 1. Each individual device gain error factor is listed in Table 2.

PRODUCT	GAIN (V/V)	R _{INT} (kΩ)					
INA199B1-Q1	50	20					
INA199B2-Q1	100	10					
INA199B3-Q1	200	5					

Table 1. Input Resistance

Table 2. Device Gain Error Factor

PRODUCT	SIMPLIFIED GAIN ERROR FACTOR
INA199B1-Q1	$\frac{20,000}{(17 \times R_{\rm S}) + 20,000}$
INA199B2-Q1	$\frac{10,000}{(9 \times R_{\rm S}) + 10,000}$
INA199B3-Q1	<u>1000</u> R _S + 1000

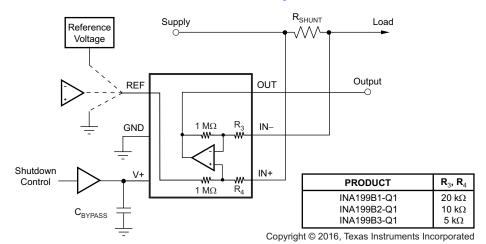
The gain error that can be expected from the addition of the external series resistors can then be calculated based on Equation 1.

For example, when using an INA199B2-Q1 and the corresponding gain error equation from Table 2, a series resistance of $10-\Omega$ results in a gain error factor of 0.991. The corresponding gain error is then calculated using Equation 1, resulting in a gain error of approximately 0.89% solely because of the external $10-\Omega$ series resistors. Using an INA199B1-Q1 with the same $10-\Omega$ series resistor results in a gain error factor of 0.991 and a gain error of 0.84% again solely because of these external resistors.

8.4.2 Shutting Down the INA199-Q1 Series

Although the INA199-Q1 series does not have a shutdown pin, the low power consumption of the device allows the output of a logic gate or transistor switch to power the INA199-Q1. This gate or switch turns on and turns off the INA199-Q1 power-supply quiescent current.

However, in current-shunt monitoring applications, there is also a concern for how much current is drained from the shunt circuit in shutdown conditions. Evaluating this current drain involves considering the simplified schematic of the INA199-Q1 in shutdown mode as shown in Figure 22.



NOTE: 1-M Ω paths from shunt inputs to the reference and the INA199-Q1 outputs.

Figure 22. Basic Circuit for Shutting Down the INA199-Q1 With a Grounded Reference



There is typically slightly more than a 1-M Ω impedance (from the combination of the 1-M Ω feedback and 5-k Ω input resistors) from each input of the INA199-Q1 to the OUT pin and to the REF pin. The amount of current flowing through these pins depends on the respective ultimate connection. For example, if the REF pin is grounded, the calculation of the effect of the 1-M Ω impedance from the shunt to ground is straightforward. However, if the reference or operational amplifier is powered when the INA199-Q1 is shut down, then the calculation is direct; instead of assuming a 1-M Ω impedance to ground, assume a 1-M Ω impedance to the reference voltage. If the reference or operational amplifier is also shut down, some knowledge of the reference or operational amplifier is required. For instance, if the reference source functions as an open circuit when not powered, little or no current flows through the 1-M Ω path.

Regarding the 1-M Ω path to the output pin, the output stage of a disabled INA199-Q1 does constitute a good path to ground. Consequently, this current is directly proportional to a shunt common-mode voltage applied across a 1-M Ω resistor.

NOTE

When the device is powered up, an additional, nearly constant, and well-matched 25 μ A of current flows in each of the inputs as long as the shunt common-mode voltage is 3 V or higher. Below 2-V common-mode, the resulting 1-M Ω resistors are the only effects from this current.

8.4.3 REF Input Impedance Effects

As with any difference amplifier, the INA199-Q1 series common-mode rejection ratio is affected by any impedance present at the REF input. This concern is not a problem when the REF pin is connected directly to most references or power supplies. When using resistive dividers from the power supply or a reference voltage, the REF pin must be buffered by an operational amplifier.

In systems where the INA199-Q1 output can be sensed differentially, such as by a differential input analog-todigital converter (ADC) or by using two separate ADC inputs, the effects of the external impedance on the REF input can be cancelled. Figure 23 shows a method of capturing the output from the INA199-Q1 by using the REF pin as a reference.

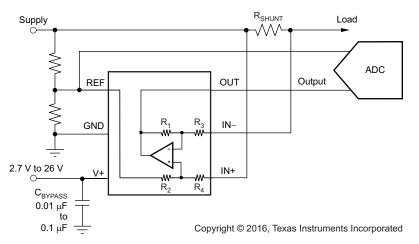


Figure 23. Sensing the INA199-Q1 to Cancel Effects of Impedance on the REF Input



8.4.4 Using the INA199-Q1 With Common-Mode Transients Above 26 V

With a small amount of additional circuitry, the INA199-Q1 series can be used in circuits subject to transients higher than 26 V, such as automotive applications. Use only zener diodes or zener-type transient absorbers (sometimes referred to as *transzorbs*); any other type of transient absorber has an unacceptable time delay. Start by adding a pair of resistors (as shown in Figure 24) as a working impedance for the zener. Keeping these resistors as small as possible is preferable, most often approximately 10 Ω . Larger values can be used with an affect on gain as discussed in the *Input Filtering* section. Many applications are satisfied with a 10- Ω resistor along with conventional zener diodes of the lowest power rating that can be found because this circuit limits only short-term transients. This combination uses the least amount of board space. These diodes can be found in packages as small as SOT-523 or SOD-523. See *TIDA-00302 Transient Robustness for Current Shunt Monitor Design Guide*, TIDU473 for more information on transient robustness and current-shunt monitor input protection.

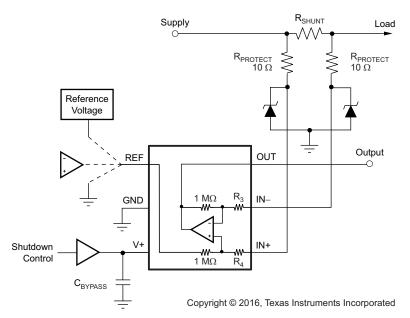


Figure 24. INA199-Q1 Transient Protection Using Dual Zener Diodes

In the event that low-power zeners do not have sufficient transient absorption capability and a higher power transzorb must be used, the most package-efficient solution then involves using a single transzorb and back-toback diodes between the device inputs. The most space-efficient solutions are dual series-connected diodes in a single SOT-523 or SOD-523 package. This method is illustrated in Figure 25. In either of these examples, the total board area required by the INA199-Q1 with all protective components is less than that of an 8-pin SOIC package, and only slightly greater than that of an 8-pin VSSOP package.



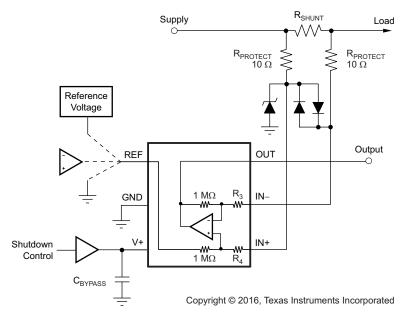


Figure 25. INA199-Q1 Transient Protection Using a Single Transzorb and Input Clamps

9 Application and Implementation

NOTE

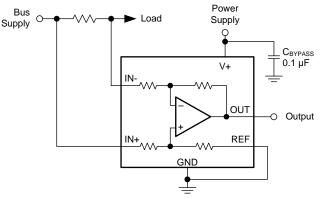
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

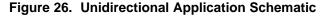
The INA199-Q1 measures the voltage developed across a current-sensing resistor when current passes through it. The ability to drive the reference pin to adjust the functionality of the output signal offers multiple configurations, as discussed throughout this section.

9.2 Typical Applications

9.2.1 Unidirectional Operation



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Typical Applications (continued)

9.2.1.1 Design Requirements

The device can be configured to monitor current flowing in one direction (unidirectional) or in both directions (bidirectional), depending on how the REF pin is configured. The most common case is unidirectional where the output is set to ground when current is not flowing by connecting the REF pin to ground; see Figure 26. When the input signal increases, the output voltage at the OUT pin increases.

9.2.1.2 Detailed Design Procedure

The linear range of the output stage is limited in how close the output voltage can approach ground under zero input conditions. In unidirectional applications where measuring very low input currents is desirable, bias the REF pin to a convenient value above 50 mV to get the output into the linear range of the device. To limit common-mode rejection errors, buffering the reference voltage connected to the REF pin is recommended.

A less frequently-used output biasing method is to connect the REF pin to the supply voltage, V+. This method results in the output voltage saturating at 200 mV below the supply voltage when a differential input signal is not present. This method is similar to the output-saturated low condition without an input signal when the REF pin is connected to ground. The output voltage in this configuration only responds to negative currents that develop negative differential input voltage relative to the device IN– pin. Under these conditions, when the differential input signal increases negatively, the output voltage moves downward from the saturated supply voltage. The voltage applied to the REF pin must not exceed the device supply voltage.

9.2.1.3 Application Curve

An example output response of a unidirectional configuration is shown in Figure 27. With the REF pin connected directly to ground, the output voltage is biased to this zero output level. The output rises above the reference voltage for positive differential input signals but cannot fall below the reference voltage for negative differential input signals because of the grounded reference voltage.

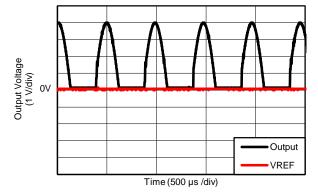


Figure 27. Unidirectional Application Output Response

INA199-Q1

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Typical Applications (continued)

9.2.2 Bidirectional Operation

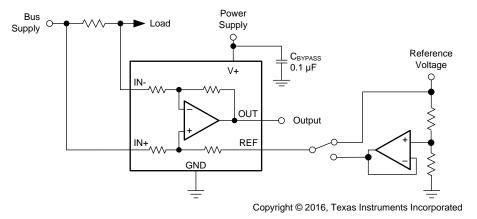


Figure 28. Bidirectional Application Schematic

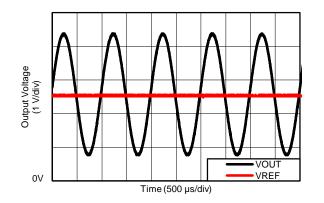
9.2.2.1 Design Requirements

The device is a bidirectional, current-sense amplifier capable of measuring currents through a resistive shunt in two directions. This bidirectional monitoring is common in applications that include charging and discharging operations where the current flow-through resistor can change directions.

9.2.2.2 Detailed Design Procedure

The ability to measure this current flowing in both directions is enabled by applying a voltage on the REF pin, as shown in Figure 28. The voltage applied to REF (V_{REF}) sets the output state that corresponds to the zero-input level state. The output then responds by rising above V_{REF} for positive differential signals (relative to the IN– pin) and falling below V_{REF} for negative differential signals. This reference voltage applied to the REF pin can be set anywhere between 0 V to V+. For bidirectional applications, V_{REF} is typically set at mid-scale for an equal signal range in both current directions. In some cases, however, V_{REF} is set at a voltage other than mid-scale when the bidirectional current and corresponding output signal do not need to be symmetrical.

9.2.2.3 Application Curve







10 Power Supply Recommendations

The input circuitry of the INA199-Q1 can accurately measure beyond its power-supply voltage, V+. For example, the V+ power supply can be 5 V, whereas the load power-supply voltage can be as high as 26 V. However, the output voltage range of the OUT pin is limited by the voltages on the power-supply pin. Furthermore, the INA199-Q1 can withstand the full input signal range up to the 26-V range in the input pins, regardless of whether the device has power applied or not.

11 Layout

11.1 Layout Guidelines

- Connect the input pins to the sensing resistor using a kelvin or 4-wire connection. This connection technique
 ensures that only the current-sensing resistor impedance is detected between the input pins. Poor routing of
 the current-sensing resistor commonly results in additional resistance present between the input pins. Given
 the very low ohmic value of the current resistor, any additional high-current carrying impedance can cause
 significant measurement errors.
- Place the power-supply bypass capacitor as close as possible to the supply and ground pins. Using a bypass capacitor with a value of 0.1 µF is recommended. Additional decoupling capacitance can be added to compensate for noisy or high-impedance power supplies.

11.2 Layout Example

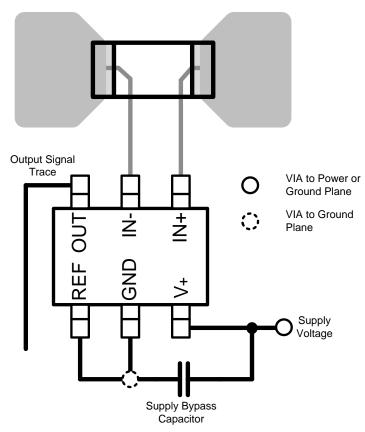


Figure 30. Recommended Layout

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12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following:

- INA199EVM User's Guide, SBOU085
- TIDA-00302 Transient Robustness for Current Shunt Monitor, TIDU473

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



19-May-2016

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
INA199B1QDCKRQ1	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	13C	Samples
INA199B2QDCKRQ1	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	13D	Samples
INA199B3QDCKRQ1	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 125	13E	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

19-May-2016

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF INA199-Q1:

Catalog: INA199

NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal Device	1	Package Drawing		SPQ	Reel Diameter		A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
INA199B1QDCKRQ1	SC70	DCK	6	3000	(mm) 178.0	W1 (mm) 9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B2QDCKRQ1	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
INA199B3QDCKRQ1	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3

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PACKAGE MATERIALS INFORMATION

20-May-2016



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
INA199B1QDCKRQ1	SC70	DCK	6	3000	180.0	180.0	18.0
INA199B2QDCKRQ1	SC70	DCK	6	3000	180.0	180.0	18.0
INA199B3QDCKRQ1	SC70	DCK	6	3000	180.0	180.0	18.0

DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AB.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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